

NPN power transistors

Features

- NPN transistors

Applications

- Audio, general purpose switching and amplifier transistors

Description

The devices are manufactured in Planar technology with "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage. The PNP types are BD242A and BD242C.

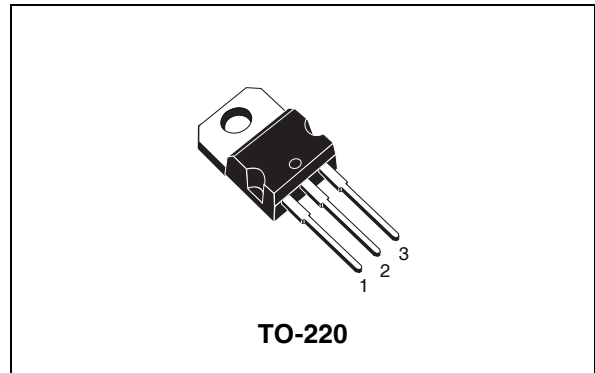


Figure 1. Internal schematic diagram

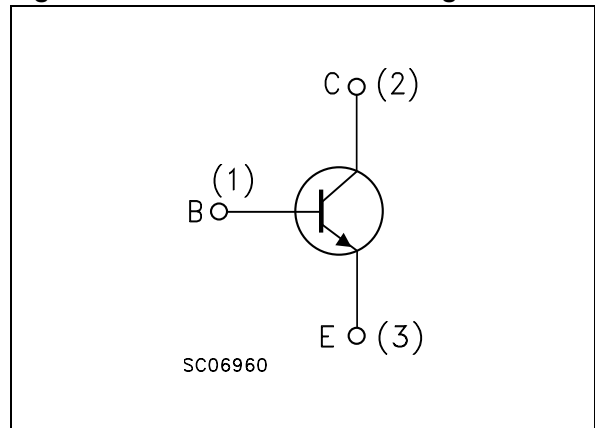


Table 1. Device summary

Order codes	Marking	Package	Packaging
BD241A	BD241A	TO-220	Tube
BD241C	BD241C	TO-220	Tube

1 Absolute maximum ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value		Unit
		BD241A	BD241C	
V_{CER}	Collector-emitter voltage ($R_{BE} = 100\Omega$)	70	115	V
V_{CEO}	Collector-emitter voltage ($I_B = 0$)	60	100	V
V_{EBO}	Emitter-base voltage ($I_C = 0$)	5		V
I_C	Collector current	3		A
I_{CM}	Collector peak current ($t_p < ms$)	5		A
I_B	Base current	1		A
P_{TOT}	Total dissipation at $T_{case} = 25^\circ C$	40		W
T_{stg}	Storage temperature	-65 to 150		$^\circ C$
T_J	Max. operating junction temperature	150		$^\circ C$

2 Electrical characteristics

(T_{case} = 25°C; unless otherwise specified)

Table 3. Electrical characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = rated V _{CEO}			0.2	mA
I _{CEO}	Collector cut-off current (I _B = 0)	for BD241A V _{CE} = 30V for BD241C V _{CE} = 60V			0.3 0.3	mA mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 5V			1	mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 30mA for BD241A for BD241C	60 100			V V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = 3A I _B = 0.6A			1.2	V
V _{BE} ⁽¹⁾	Base-emitter voltage	I _C = 3A V _{CE} = 4V			1.8	V
h _{FE} ⁽¹⁾	DC current gain	I _C = 1A V _{CE} = 4V I _C = 3A V _{CE} = 4V	25 10			

1. Pulsed duration = 300 ms, duty cycle ≥ 1.5%.

2.1 Electrical characteristic (curves)

Figure 2. Safe operating area

Figure 3. Derating curve

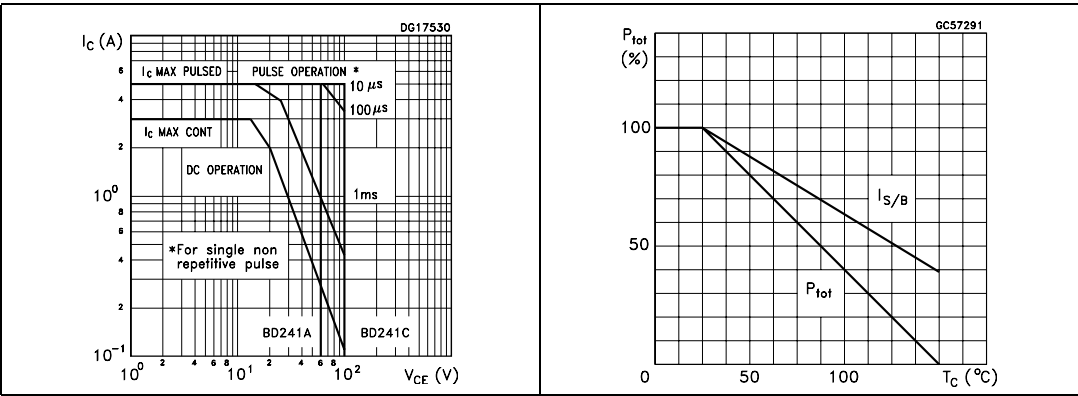


Figure 4. DC current gain

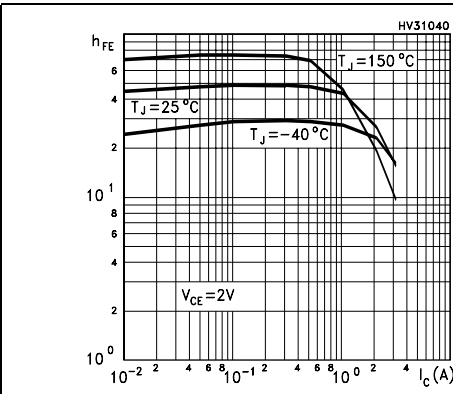


Figure 5. DC current gain

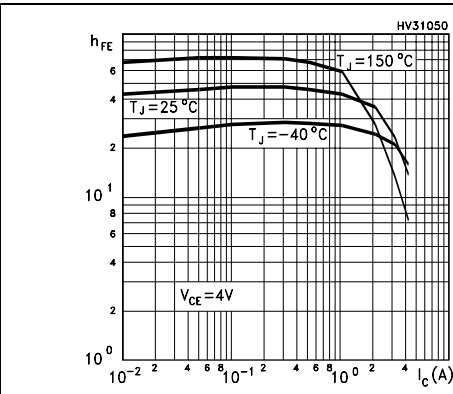


Figure 6. Collector-emitter saturation voltage

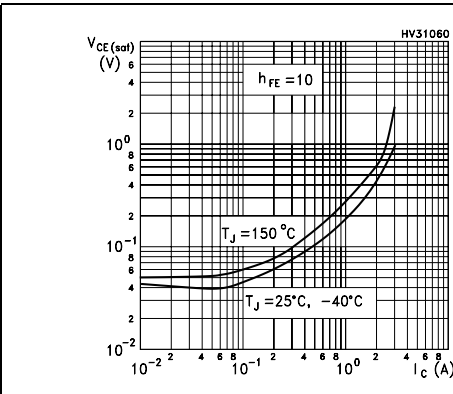


Figure 7. Base-emitter saturation voltage

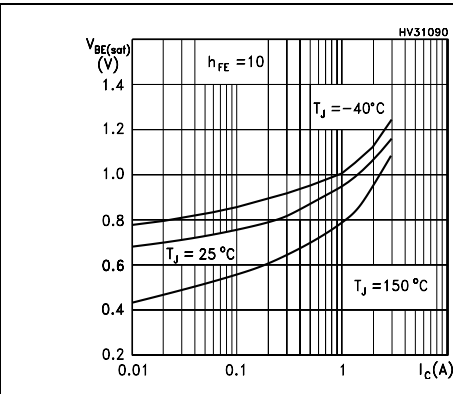


Figure 8. Base-emitter on voltage

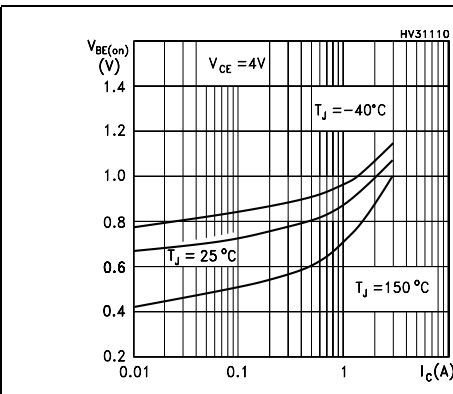


Figure 9. Resistive load switching time

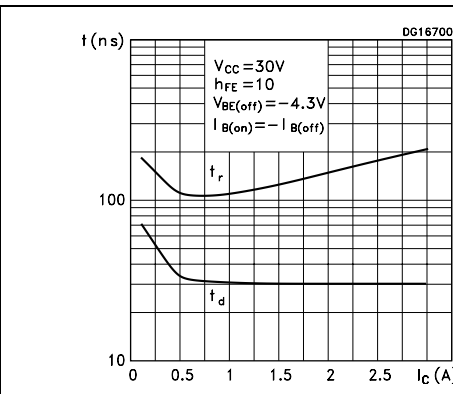
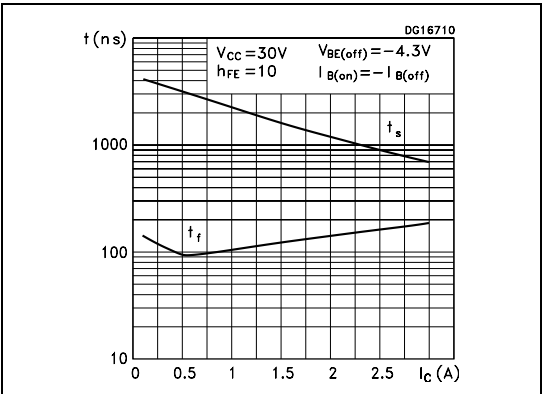
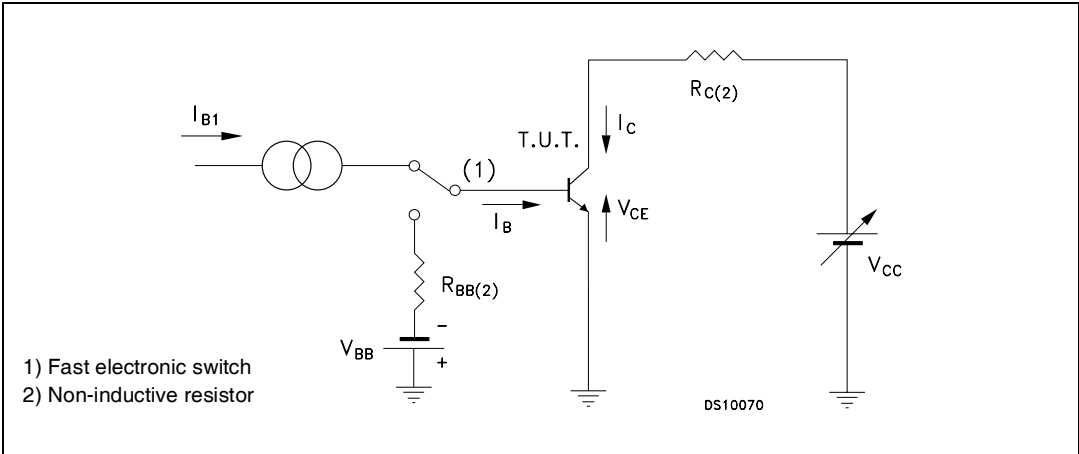


Figure 10. Resistive load switching time



2.2 Test circuits

Figure 11. Resistive load switching test circuit

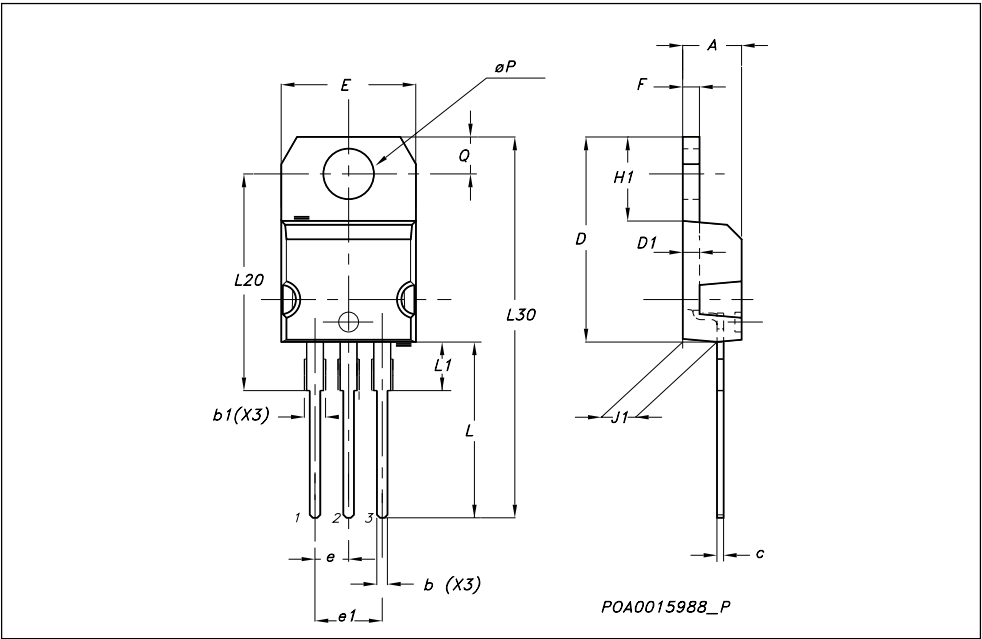


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect . The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

TO-220 Mechanical data

DIM.	mm.		
	MIN.	TYP	MAX.
A	4.40		4.60
b	0.61		0.88
b1	1.14		1.70
c	0.49		0.70
D	15.25		15.75
D1		1.27	
E	10		10.40
e	2.40		2.70
e1	4.95		5.15
F	1.23		1.32
H1	6.20		6.60
J1	2.40		2.72
L	13		14
L1	3.50		3.93
L20		16.40	
L30		28.90	
øP	3.75		3.85
Q	2.65		2.95



4 Revision history

Table 4. Revision history

Date	Revision	Changes
01-Dec-2000	1	Initial Release
10-Jul-2007	2	Figure 2 and figure 3, have been added.

Please Read Carefully:

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.

UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2007 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan - Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

www.st.com